UNISONIC TECHNOLOGIES CO., LTD

4N70 Power MOSFET

4.4A, 700V N-CHANNEL POWER MOSFET

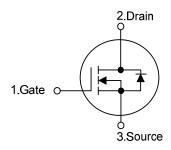
DESCRIPTION

The UTC 4N70 is a high voltage power MOSFET and is designed to have better characteristics, such as fast switching time, low gate charge, low on-state resistance and high rugged avalanche. This high speed switching power MOSFET is usually used in power supplies, PWM motor controls, high efficient DC to DC converters and bridge circuits.

FEATURES

- * $R_{DS(ON)}$ < 2.8 Ω @ V_{GS} = 10 V
- * Ultra Low Gate Charge (Typical 15nC)
- * Low Reverse Transfer Capacitance (C_{RSS} = Typical 8.0 pF)
- * Fast Switching Capability
- * Avalanche Energy Specified
- * Improved dv/dt Capability, High Ruggedness

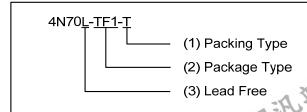
SYMBOL



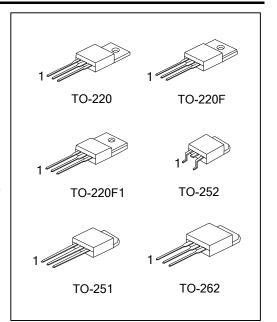
ORDERING INFORMATION

Ordering Number		Dookogo	Pin Assignment			Dooking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
4N70L-TA3-T	4N70G-TA3-T	TO-220	G	D	S	Tube	
4N70L-TF1-T	4N70G-TF1-T	TO-220F1	G	D	S	Tube	
4N70L-TF3-T	4N70G-TF3-T	TO-220F	G	D	S	Tube	
4N70L-TM3-T	4N70G-TM3-T	TO-251	G	D	S	Tube	
4N70L-TN3-R	4N70G-TN3-R	TO-252	G	D	S	Tape Reel	
4N70L-T2Q-T	4N70G-T2Q-T	TO-262	G	D	S	Tube	

Note: Pin Assignment: G: Gate D: Drain S: Source



- (1) T: Tube
- 1: TO-220F1, TF3: TO-220F,
 - TM3: TO-251, TN3: TO-252, T2Q: TO-262
- (3) L: Lead Free, G: Halogen Free,



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MARKING INFORMATION

PACKAGE		MARKING
TO-220 TO-220F TO-220F1	TO-251 TO-252 TO-262	UTC 4N70 ☐ C: Lead Free → G: Halogen Free → Data Code

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C, unless otherwise specified)

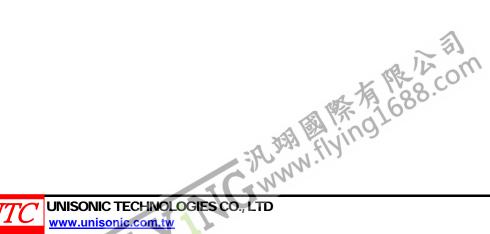
PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		V_{DSS}	700	V
Gate-Source Voltage		V_{GSS}	±30	V
Avalanche Current (Note 2)		I _{AR}	4.4	Α
Drain Current	Continuous	I _D	4.4	Α
	Pulsed (Note 2)	I _{DM}	17.6	Α
Avalanche Energy	Single Pulsed (Note 3)	E _{AS}	260	mJ
	Repetitive (Note 2)	E _{AR}	10.6	mJ
Peak Diode Recovery dv/dt (Note 4)		dv/dt	4.5	V/ns
Power Dissipation	TO-220/TO-262		106	
	TO-220F/TO-220F1	P_{D}	36	W
	TO-251/ TO-252		49	
Junction Temperature		ΤJ	+150	°C
Operating Temperature		T _{OPR}	-55 ~ + 150	°C
Storage Temperature		T _{STG}	-55 ~ +150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

- 2. Repetitive Rating : Pulse width limited by maximum junction temperature
- 3. L = 26.9mH, I_{AS} = 4.4A, V_{DD} = 50V, R_G = 25 Ω , Starting T_J = 25°C
- 4. $I_{SD} \le 4.4A$, di/dt $\le 200A/\mu s$, $V_{DD} \le BV_{DSS}$, Starting $T_J = 25^{\circ}C$

THERMAL DATA

PARAMETER		OVALDOL	DATINGO	LINUT	
PAR	AMETER	SYMBOL	RATINGS	UNIT	
Junction to Ambient	TO-220/TO-220F TO-220F1/TO-262	θја	62.5	°C/W	
	TO-251/ TO-252		110		
Junction to Case	TO-220/TO-262		1.18		
	TO-220F/TO-220F1	θ_{JC}	3.47	°C/W	
	TO-251/ TO-252		2.55		



ELECTRICAL CHARACTERISTICS (T_A =25°C, unless otherwise specified)

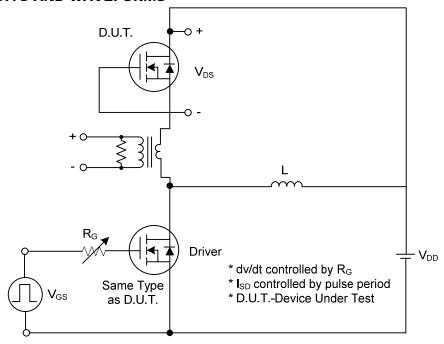
PARAMETER		SYMBOL	TEST CONDITIONS		TYP	MAX	UNIT
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage		BV_{DSS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	700			V
Drain-Source Leakage Current		I _{DSS}	V _{DS} = 700 V, V _{GS} = 0 V			10	μΑ
Gate-Source Leakage Current	Forward	I _{GSS}	$V_{GS} = 30 \text{ V}, V_{DS} = 0 \text{ V}$			100	A
	Reverse		$V_{GS} = -30 \text{ V}, V_{DS} = 0 \text{ V}$			-100	nA
Breakdown Voltage Temperature Coefficient		$\triangle BV_{DSS} \! / \triangle T_J$	I _D = 250μA, Referenced to 25°C		0.6		V/°C
ON CHARACTERISTICS							
Gate Threshold Voltage		$V_{GS(TH)}$	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2.0		4.0	V
Static Drain-Source On-State Res	sistance	R _{DS(ON)}	V _{GS} = 10 V, I _D = 2.2 A		2.6	2.8	Ω
DYNAMIC CHARACTERISTICS							
Input Capacitance		C _{ISS}	V 05.V.V 0.V		520	670	pF
Output Capacitance		Coss	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V},$		70	90	pF
Reverse Transfer Capacitance	Reverse Transfer Capacitance		f = 1MHz		8	11	pF
SWITCHING CHARACTERISTIC	S						
Turn-On Delay Time		t _{D(ON)}	V _{DD} = 350V, I _D = 4.4A,		13	35	ns
Turn-On Rise Time		t_R			45	100	ns
Turn-Off Delay Time		$t_{D(OFF)}$	$R_G = 25\Omega$ (Note 1, 2)		25	60	ns
Turn-Off Fall Time		t_{F}			35	80	ns
Total Gate Charge		Q_G	V _{DS} = 560V, I _D = 4.4A, -V _{GS} = 10 V (Note 1, 2)		15	20	nC
Gate-Source Charge		Q_GS			3.4		nC
Gate-Drain Charge	Gate-Drain Charge		VGS= 10 V (Note 1, 2)		7.1		nC
SOURCE- DRAIN DIODE RATIN	GS AND CI	HARACTERIST	rics				
Drain-Source Diode Forward Voltage		V_{SD}	$V_{GS} = 0 \text{ V}, I_{S} = 4.4 \text{ A}$			1.4	V
Maximum Continuous Drain-Sour	ce Diode					4.4	Α
Forward Current		I _S				4.4	^
Maximum Pulsed Drain-Source Diode		I _{SM}				17.6	Α
Forward Current		ISM				17.0	^
Reverse Recovery Time		t _{rr}	$V_{GS} = 0 \text{ V}, I_{S} = 4.4 \text{ A},$		250		ns
Reverse Recovery Charge		Q_{RR}	dI/dt = 100 A/μs (Note 1)		1.5		μC

Notes: 1. Pulse Test: Pulse width ≤ 300µs, Duty cycle ≤ 2%

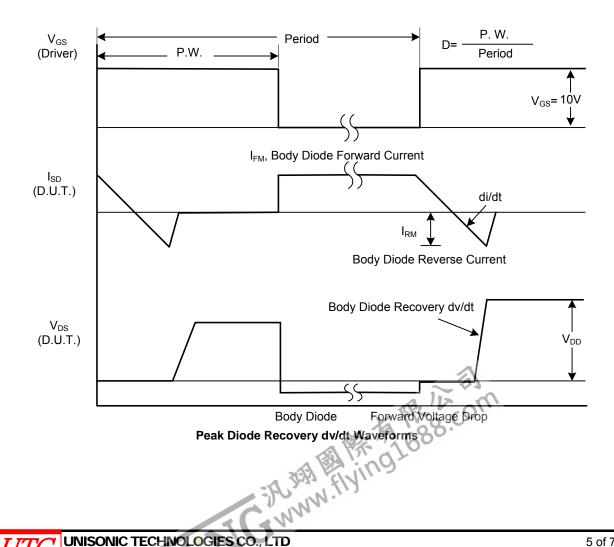
2. Essentially independent of operating temperature



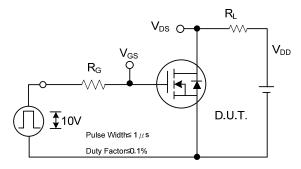
TEST CIRCUITS AND WAVEFORMS



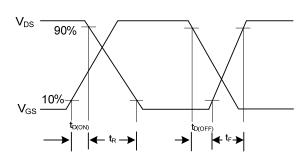
Peak Diode Recovery dv/dt Test Circuit



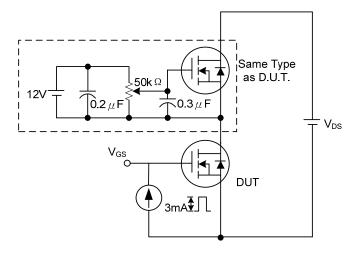
TEST CIRCUITS AND WAVEFORMS (Cont.)



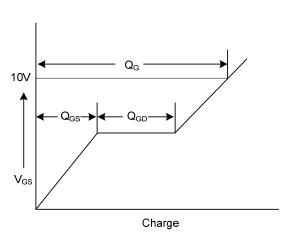
Switching Test Circuit



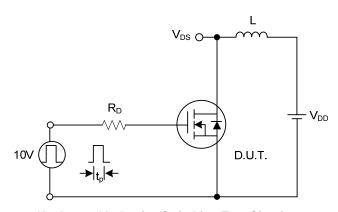
Switching Waveforms



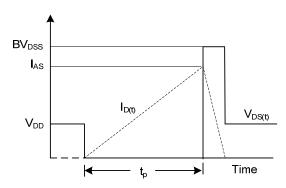
Gate Charge Test Circuit



Gate Charge Waveform

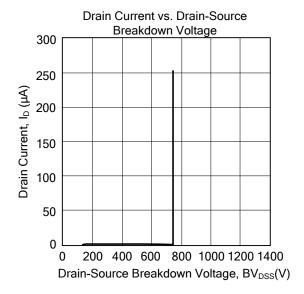


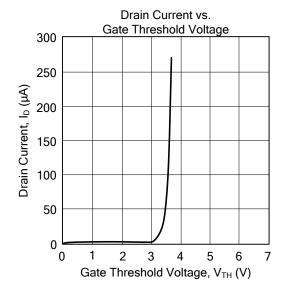
Unclamped Inductive Switching Test Circuit

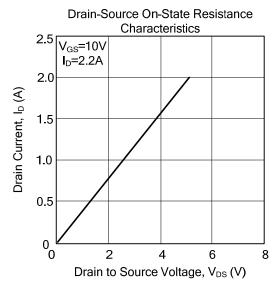


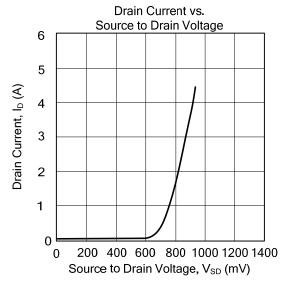
Unclamped Inductive Switching Waveforms

■ TYPICAL CHARACTERISTICS









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